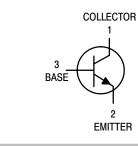
# **VHF Transistor**

**NPN Silicon** 



## **ON Semiconductor**<sup>™</sup>

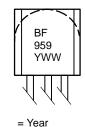
### http://onsemi.com





CASE 29 STYLE 21

### MARKING DIAGRAM



Y = Year W = Work Week

## ORDERING INFORMATION

Device	Package	Shipping
BF959	TO-92	5000 Units/Box
BF959ZL1	TO-92	2000/Ammo Pack
BF959RL1	TO-92	2000 Units/Box

#### MAXIMUM RATINGS

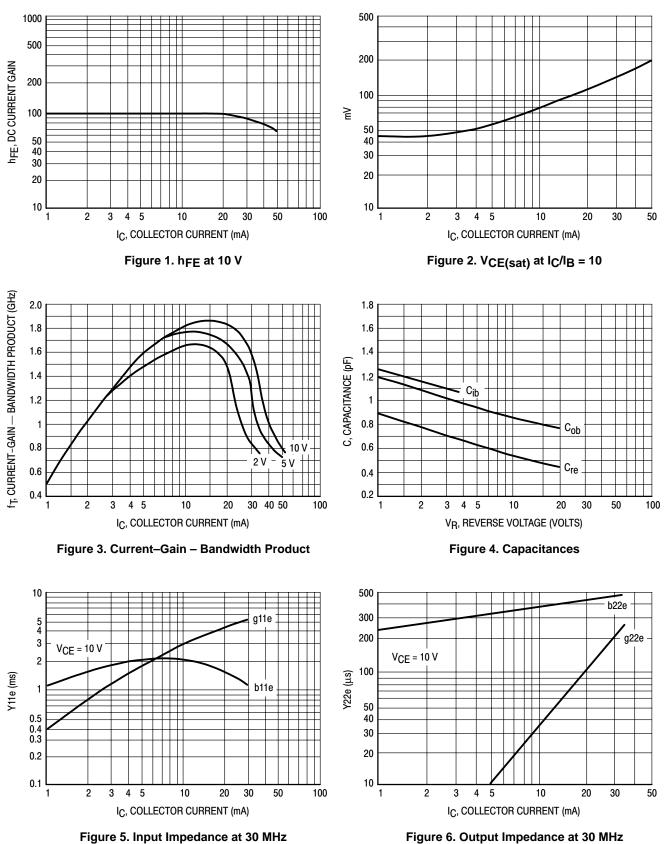
Rating	Symbol	Value	Unit
Collector-Emitter Voltage	VCEO	20	Vdc
Collector–Base Voltage	VCBO	30	Vdc
Emitter-Base Voltage	VEBO	3.0	Vdc
Collector Current – Continuous	۱C	100	mAdc
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	PD	625 5.0	mW mW/°C
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	PD	1.5 12	Watts mW/°C
Operating and Storage Junction Temperature Range	TJ, T <sub>stg</sub>	–55 to +150	°C

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{ heta}JA$	200	°C/W
Thermal Resistance, Junction to Case	R <sub>θ</sub> JC	83.3	°C/W

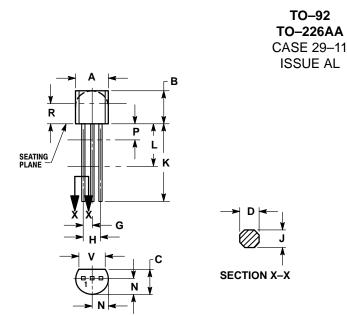
# ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	•				
Collector-Emitter Breakdown Voltage ( $I_C = 1.0 \text{ mAdc}, I_B = 0$ )	V(BR)CEO	20	-	_	Vdc
Collector–Base Breakdown Voltage ( $I_C = 10 \ \mu Adc$ , $I_E = 0$ )	V(BR)CBO	30	-	-	Vdc
Emitter–Base Breakdown Voltage ( $I_E = 10 \ \mu Adc$ , $I_C = 0$ )	V(BR)EBO	3.0	-	-	Vdc
Collector Cutoff Current ( $V_{CB} = 20 \text{ Vdc}, I_E = 0$ )	ICBO	-	-	100	nAdc
ON CHARACTERISTICS					
DC Current Gain $(I_C = 5.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc})$ $(I_C = 20 \text{ mAdc}, V_{CE} = 10 \text{ Vdc})$	hFE	35 40			_
Collector–Emitter Saturation Voltage ( $I_C = 30$ mAdc, $I_B = 2.0$ mAdc)	V <sub>CE(sat)</sub>	-	-	1.0	Vdc
Base–Emitter Saturation Voltage ( $I_C$ = 30 mAdc, $I_B$ = 2.0 mAdc)	V <sub>BE(sat)</sub>	-	-	1.0	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Current–Gain – Bandwidth Product ( $I_C = 20$ mAdc, $V_{CE} = 10$ Vdc, f = 100 MHz) ( $I_C = 30$ mAdc, $V_{CE} = 10$ Vdc, f = 100 MHz)	fT	700 600			MHz
Common Emitter Feedback Capacitance $(V_{CB} = 10 \text{ Vdc}, P_f = 0, f = 10 \text{ MHz})$	C <sub>re</sub>	-	0.65	-	pF
Noise Figure (I <sub>C</sub> = 4.0 mA, V <sub>CE</sub> = 10 V, R <sub>S</sub> = 50 $\Omega$ , f = 200 MHz)	Nf	-	3.0	-	dB





#### PACKAGE DIMENSIONS



NOTES:

DIMENSIONING AND TOLERANCING PER ANSI 1.

2.

CONTROLLING DIMENSION: INCH. CONTOUR OF PACKAGE BEYOND DIMENSION R 3

IS UNCONTROLLED. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM. 4.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Η	0.095	0.105	2.42	2.66
L	0.015	0.020	0.39	0.50
Κ	0.500		12.70	
L	0.250		6.35	
Ν	0.080	0.105	2.04	2.66
Ρ		0.100		2.54
R	0.115		2.93	
۷	0.135		3.43	

STYLE 21:		STYLE 14:	
PIN 1.	COLLECTOR	PIN 1.	EMITTER
2.	EMITTER	2.	COLLECTOR
3.	BASE	3.	BASE

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